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09/769,490	01/26/2001	Kenji Itoga	49657-961 5521	
75	90 03/27/2003			
McDERMOT	T, WILL & EMERY	EXAMINER		
600 13th Street, Washington, DO			KAO, CHIH	CHENG G
			ART UNIT	PAPER NUMBER
			2882	
			DATE MAILED: 03/27/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	14	Application No.	Applicant(s)	74 47		
		09/769,490	ITOGA ET AL.			
Office Action Su	กลาง	Examiner	Art Unit			
		Chih-Cheng Glen Kao	2882			
The MAILING DATE of this Period for Reply	s communication ap	pears on the cover sheet	with the correspondence at	ddress		
A SHORTENED STATUTORY P THE MAILING DATE OF THIS C  - Extensions of time may be available under t after SIX (6) MONTHS from the mailing date  - If the period for reply specified above, the - Failure to reply within the set or extended p - Any reply received by the Office later than th earned patent term adjustment. See 37 CFI  Status  1) Responsive to communic	communication. the provisions of 37 CFR 1 to of this communication. than thirty (30) days, a re- maximum statutory period- teriod for reply will, by statu- turee months after the mailing 1.704(b).  ation(s) filed on 25	.136(a). In no event, however, may only within the statutory minimum of I will apply and will expire SIX (6) Net, cause the application to become ag date of this communication, eve	y a reply be timely filed thirty (30) days will be considered time MONTHS from the mailing date of this of ABANDONED (35 U.S.C. § 133).			
2a) ☐ This action is <b>FINAL</b> .	2b)⊠ T	his action is non-final.				
<ul> <li>Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.</li> <li>Disposition of Claims</li> </ul>						
4)⊠ Claim(s) <u>1-18,20-43 and 4</u>	<del></del> ·	• .,				
4a) Of the above claim(s) _		awn from consideration.				
5) Claim(s) is/are allow						
6)⊠ Claim(s) <u>1-18,20-43 and 4</u>	<del></del>	1.				
7) Claim(s) is/are obje						
8) ☐ Claim(s) are subjec Application Papers	t to restriction and/	or election requirement.				
9)☐ The specification is objecte	d to by the Examin	er.				
10)⊠ The drawing(s) filed on <u>26 .</u>	<i>lanuary 2001</i> is/are	e: a)⊠ accepted or b)□ o	bjected to by the Examiner.			
,,,			eyance. See 37 CFR 1.85(a).			
11)☐ The proposed drawing corre			disapproved by the Examir	ner.		
If approved, corrected drawi						
12)☐ The oath or declaration is o		xaminer.				
Priority under 35 U.S.C. §§ 119 and						
13) Acknowledgment is made	`	n priority under 35 U.S.	C. § 119(a)-(d) or (f).			
a)⊠ All b)□ Some * c)□ □	None of:					
1.⊠ Certified copies of th	e priority documer	its have been received.				
2. ☐ Certified copies of the	2. Certified copies of the priority documents have been received in Application No					
<ul> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>						
14)☐ Acknowledgment is made of	a claim for domes	tic priority under 35 U.S.	C. § 119(e) (to a provisiona	al application).		
a) ☐ The translation of the f 15)☐ Acknowledgment is made o		• •				
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawin 3) Information Disclosure Statement(s) (P		5) 🔲 Notice	ew Summary (PTO-413) Paper No of Informal Patent Application (PT			
J.S. Patent and Trademark Office PTO-326 (Rev. 04-01)	Office A	Action Summary	Part of	f Paper No. 18		

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#### **DETAILED ACTION**

## Information Disclosure Statement

Since, the Supplemental Information Disclosure Statement filed January 16, 2003, is a corrected version of the PTO-1449 forms filed on November 25, 2002, the Examiner will consider the references listed in the corrected PTO-1449 forms filed January 16, 2003, only. Also note that in the PTO-1449 form filed 9/18/2002, the foreign patent document 4634643 was considered as a US Patent document, and written in above, as noted in the PTO-1449.

# Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1, 2, 4, 14, 15, 24, 25, 27, and 37-39 are rejected under 35 U.S.C. 103(a) as obvious over Itabashi (JP 11-014800) in view of Bearden et al. (Reviews of Modern Physics).
- 3. With regards to claims 1 and 24, Itabashi discloses an x-ray exposure apparatus and method (Paragraph [0001]) comprising: an incidence step to an x-ray mirror and providing light having a component and peak in wavelength ranging from 0.45 nm through 0.7 nm (Paragraph [0012]).

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However, Itabashi does not specifically disclose the material having an absorption edge only in a wavelength region other than 0.4 nm through 0.7 nm.

Itabashi further teaches a material such as ruthenium in another embodiment (Paragraph [0011]). Bearden et al. teaches ruthenium with an absorption edge only in a wavelength region other than 0.4 nm through 0.7 nm (Row in table containing element Ru). Note that when converting each of the edges from energy to wavelength using the equation for energy of photons  $(E = hc/\lambda)$ , wavelengths occur in a region other than 0.4 nm through 0.7 nm.

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have use ruthenium of Itabashi with the device and method of Itabashi, since one would be motivated to use a metal to have a higher reflection factor compared to light matter (Paragraph [0011]) as implied by Itabashi.

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have the absorption edges of Bearden et al. with the device and method of Itabashi, since these properties were well known in the art at the time the invention was made as shown by Bearden et al. One would be motivated to have these properties so there is less loss of a signal at a particular wavelength.

- 4. With regards to claims 2 and 25, Itabashi further discloses an x-ray incidence step using a synchrotron radiation source (Paragraph [0016]).
- 5. With regards to claim 4 and 27, Itabashi further discloses the mirror with ruthenium (Paragraph [0011]).

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6. With regards to claims 14, 15, and 37, and 38, Itabashi further discloses the outgoing and incidence directions and optical axes of x-rays being substantially identical (Fig. 1).

- 7. With regards to claim 39, Itabashi further discloses an exposure step to manufacture a semiconductor device (Paragraph [0001]).
- 8. Claims 3 and 26 are rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Bearden et al. as respectively applied to claims 1 and 24 above, and further in view of Uzawa et al. (US Patent 5524131).

Itabashi in view of Bearden et al. suggest a device and method as recited above.

However, Itabashi does not specifically disclose absorbing at least 90% of x-rays of a wavelength region of less than 0.3 nm.

Uzawa et al. teaches absorbing at least 90% of x-rays of a wavelength region of less than 0.3 nm (Fig. 6B).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have the absorption of at least 90% of x-rays with wavelengths less than 0.3 nm of Uzawa et al. with the suggested device and method of Itabashi in view of Bearden et al., since one would be motivated to differ the absorption factor to raise exposure luminous efficacy as shown by Itabashi (Paragraphs [0005] and [0006]) and since these properties are intrinsic to the mirror itself as implied from Uzawa et al. (col. 16, lines 60-65).

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9. Claims 5, 7, 28, and 30 are rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Bearden et al. as respectively applied to claims 1 and 24 above, and further in view of Oshino (US Patent 5677939).

Itabashi in view of Bearden et al. suggests a device and method as recited above.

However, Itabashi does not specifically disclose a converging mirror for converging.

Oshino teaches a converging mirror for converging (Fig. 1, #3).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have a converging mirror of Oshino with the suggested device and method of Itabashi in view of Bearden et al., since one would be motivated to use it to illuminate a surface in an arcuate pattern with uniform intensity as implied from Oshino (Abstract).

10. Claims 6, 8, 29, and 31 are rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Bearden et al., as respectively applied to claims 1 and 24 above, and further in view of Sumiya (JP 3-120714).

Itabashi in view of Bearden et al. suggests a device and method as recited above.

However, Itabashi does not specifically disclose a magnifying mirror for magnifying the area of a region being irradiated.

Sumiya teaches a magnifying mirror for magnifying the area of a region being irradiated (Abstract, Constitution, last 5 lines).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have a magnifying mirror of Sumiya with the suggested device and

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method of Itabashi in view of Bearden et al., since one would be motivated to use it to enlarge a radiation area for more exposure as implied from Sumiya (Abstract, Purpose).

11. Claims 9, 10, 32, and 33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Itabashi in view of Bearden et al. as applied to claims 1 and 24 above and further in view of Haisma et al. (US Patent 5622525).

Itabashi in view of Bearden et al. suggests an apparatus and method as described above.

However, Hasegawa et al. does not seem to specifically disclose a mirror as mechanically or chemically polished.

Haisma et al. teaches a mirror as mechanically or chemically polished (col. 5, lines 1-5, and col. 5, lines 11-26).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have the mirrors polished mechanically or chemically of Haisma et al. with the suggested device and method of Itabashi in view of Bearden et al., since one may be motivated to polish a mirror to prevent irregularities as shown by Itabashi (Paragraph [0003]) for more controlled exposure, or for strict requirements imposed on the condition of the surface as implied from Haisma et al. (col. 5, liens 10-26).

12. Claims 13, 36, and 40-43 are rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Bearden et al. as respectively applied to claims 1 and 24 above, and further in view of Watanabe (JP 10-083955).

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13. With regards to claims 13 and 36, Itabashi in view of Bearden et al. suggests a device and method as recited above.

However, Itabashi does not specifically disclose a plurality of mirrors.

Watanabe teaches a plurality of mirrors (Abstract, Solution).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have a plurality of mirrors of Watanabe with the suggested device and method of Itabashi in view of Bearden et al., since one would be motivated to use it to enchase the throughput of the light for exposure as implied from Watanabe (Abstract, Problem to be Solved).

14. With regards to claims 40 and 42, for reasons of being concise, Itabashi in view of Bearden et al. suggests a device and method as recited above. Itabashi further discloses an x-ray incidence step using a synchrotron radiation source (Paragraph [0016]), along with outgoing radiation from the source and reflected light from the mirror are substantially identical (Fig. 1).

However, Itabashi does not specifically disclose a plurality of mirrors.

Watanabe teaches a plurality of mirrors (Abstract, Solution).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have a plurality of mirrors of Watanabe with the suggested device and method of Itabashi in view of Bearden et al., since one would be motivated to use it to enchase the throughput of the light for exposure as implied from Watanabe (Abstract, Problem to be Solved).

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15. With regards to claims 41 and 42, Itabashi further discloses the outgoing optical axes of x-rays from the source and mirror being substantially identical (Fig. 1).

16. Claims 11, 12, 34, and 35 are rejected under 35 U.S.C. 103(a) as being unpatentable over Itabashi in view of Bearden et al. as applied to claims 1 and 24 above, and further in view of Rostoker et al. (US Patent 5374974).

Itabashi in view of Bearden et al. suggests a device and method as recited above.

However, Itabashi et al. does not specifically disclose an x-ray mask comprising a membrane of beryllium having an absorption edge only in either one of a wavelength region of less than 0.45 nm and a wavelength region exceeding 0.7 nm as to x-rays, and an absorber having an absorption edge in a wavelength region of at least 0.6 nm and less than 0.85 nm.

Rostoker et al. teaches an x-ray mask comprising a membrane of beryllium (col. 4, lines 65-69), and an absorber with a material such as tungsten, (col. 5, lines 4-10). Bearden et al. further teaches beryllium with an absorption edge only in a wavelength region other than 0.4 nm through 0.7 nm (Row in table containing element Be) as well as tungsten with an absorption edge in a wavelength region of at least 0.6 nm and less than 0.85 nm. Note that when converting each of the edges from energy to wavelength using the equation for energy of photons (E =  $hc/\lambda$ ), wavelengths occur in the above said regions.

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have the mask of Rostoker et al. with the absorption properties of Bearden et al., since these properties were well known in the art at the time the invention was made as shown by Bearden et al.

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Secondly, it would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have the mask of Rostoker et al. with the absorption properties of Bearden et al. and with the x-ray exposure apparatus and method of Itabashi in view of Bearden et al., since it would have only involved routine skill and routine experimentation to discover the optimum or workable ranges of a mask in combination with a mirror for an x-ray exposure apparatus. One would be motivated to combine the mask with the mirror because one would want to insure that the intended wavelengths, which reflected from the mirror, pass through the mask to reach the sample, while unwanted wavelength regions are absorbed by the mask. One would be motivated to use the mask of Rostoker et al. for its good transparency and absorbance as implied from Rostoker et al. (col. 10, lines 12-69 to col. 11, lines 1-40).

- 17. Claims 16 and 17 are rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Yanagihara et al. (JP 06-194497).
- 18. With regards to claim 16, Itabashi discloses an x-ray mirror providing light having a component and peak in wavelength ranging from 0.45 nm through 0.7 nm (Paragraph [0012]).

However, Itabashi does not specifically disclose boron nitride.

Yanagihara et al. teaches an x-ray mirror containing boron nitride (Title).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to use boron nitride of Yanagihara et al. with the device of Itabashi, since it would be within the general skill of a worker in the art to select a known material on the basis of

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its suitability for the intended use. One would be motivated to use boron nitride to make it more heat resistant (Abstract) as implied from Yanagihara et al.

- 19. With regards to claim 17, Itabashi further discloses an x-ray incidence step using a synchrotron radiation source (Paragraph [0016]).
- 20. Claim 18 is rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Yanagihara et al. as respectively applied to claim 16 above, and further in view of Uzawa et al.

Itabashi in view of Yanagihara et al. suggest a device and method as recited above.

However, Itabashi does not specifically disclose absorbing at least 90% of x-rays of a wavelength region of less than 0.3 nm.

Uzawa et al. teaches absorbing at least 90% of x-rays of a wavelength region of less than 0.3 nm (Fig. 6B).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have the absorption of at least 90% of x-rays with wavelengths less than 0.3 nm of Uzawa et al. with the suggested device and method of Itabashi in view of Yanagihara et al., since one would be motivated to differ the absorption factor to raise exposure luminous efficacy as shown by Itabashi (Paragraphs [0005] and [0006]) and since these properties are intrinsic to the mirror itself as implied from Uzawa et al. (col. 16, lines 60-65).

21. Claim 20 is rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Yanagihara et al., as respectively applied to claim 16 above, and further in view of Oshino.

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Itabashi in view of Yanagihara et al. suggests a device as recited above.

However, Itabashi does not specifically disclose a converging mirror for converging.

Oshino teaches a converging mirror for converging (Fig. 1, #3).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have a converging mirror of Oshino with the suggested device and method of Itabashi in view of Yanagihara et al., since one would be motivated to use it to illuminate a surface in an arcuate pattern with uniform intensity as implied from Oshino (Abstract).

22. Claim 21 is rejected under 35 U.S.C. 103(a) as obvious over Itabashi in view of Yanagihara et al. as respectively applied to claim 16 above, and further in view of Sumiya.

Itabashi in view of Yanagihara et al. suggests a device as recited above.

However, Itabashi does not specifically disclose a magnifying mirror for magnifying the area of a region being irradiated.

Sumiya teaches a magnifying mirror for magnifying the area of a region being irradiated (Abstract, Constitution, last 5 lines).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have a magnifying mirror of Sumiya with the suggested device and method of Itabashi in view of Yanagihara et al., since one would be motivated to use it to enlarge a radiation area for more exposure as implied from Sumiya (Abstract, Purpose).

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23. Claims 22 and 23 are rejected under 35 U.S.C. 103(a) as being unpatentable over Itabashi in view of Yanagihara et al. as applied to claims 16 above and further in view of Haisma et al.

Itabashi in view of Yanagihara et al. suggests a device as recited above.

However, Hasegawa et al. does not seem to specifically disclose a mirror as mechanically or chemically polished.

Haisma et al. teaches a mirror as mechanically or chemically polished (col. 5, lines 1-5, and col. 5, lines 11-26).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have the mirrors polished mechanically or chemically of Haisma et al. with the suggested device and method of Itabashi in view of Yanagihara et al., since one may be motivated to polish a mirror to prevent irregularities as shown by Itabashi (Paragraph [0003]) for more controlled exposure, or for strict requirements imposed on the condition of the surface as implied from Haisma et al. (col. 5, liens 10-26).

24. Claims 46-49 are rejected under 35 U.S.C. 103(a) as being unpatentable over Itabashi in view of Bearden et al. as applied to claims 1 and 24 above and further in view of Hasegawa (JP 11-084098).

Itabashi in view of Bearden et al. suggests an apparatus and method as described above. Itabashi further discloses means for altering a peak wavelength (Figures 2 and 3).

However, Hasegawa et al. does not seem to specifically disclose maintaining a direction or optical axis.

Hasegawa teaches maintaining a direction or optical axis (Abstract, Solution).

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It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to have maintain the optical axis or direction of Hasegawa with the suggested device and method of Itabashi in view of Bearden et al., since one may be motivated to use it for supplying x-ray s with a uniform intensity distribution by a high intensity as implied from Hasegawa.

## Response to Arguments

- 25. Applicant's arguments with respect to claims 1-18, 20-43, and 46-49 have been considered but are most in view of the new ground(s) of rejection.
- 26. With regards to Itabashi, Itabashi chooses a peak wavelength between 0.45 and 0.7 nm (Figs. 2 and 3).

### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Chih-Cheng Glen Kao whose telephone number is (703) 605-5298. The examiner can normally be reached on M - Th (8 am to 5 pm).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert Kim can be reached on (703) 305-3492. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7724 for After Final communications.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

gk March 23, 2003